

$$I_{F(AV)} = 3.0\text{Amp}$$

$$V_R = 100\text{V}$$

#### Major Ratings and Characteristics

Characteristics	Values	Units
$I_{F(AV)}$ Rectangular waveform	3.0	A
$V_{RRM}$	100	V
$I_{FSM}$ @ $t_p = 5\mu\text{s}$ sine	800	A
$V_F$ @ 3.0Apk, $T_J = 125^\circ\text{C}$	0.62	V
$T_J$ range	- 55 to 175	$^\circ\text{C}$

#### Description/ Features

The 30BQ100 surface-mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Small foot print, surface mountable
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability

#### Case Styles



SMC



## Voltage Ratings

Part number	30BQ100
$V_R$ Max. DC Reverse Voltage (V)	100
$V_{RWM}$ Max. Working Peak Reverse Voltage (V)	

## Absolute Maximum Ratings

Parameters	30BQ	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current	3.0	A	50% duty cycle @ $T_L = 148^\circ\text{C}$ , rectangular wave form
	4.0		50% duty cycle @ $T_L = 138^\circ\text{C}$ , rectangular wave form
$I_{FSM}$ Max. Peak One Cycle Non-Repetitive Surge Current	800	A	5 $\mu\text{s}$ Sine or 3 $\mu\text{s}$ Rect. pulse
	70		10ms Sine or 6ms Rect. pulse
$E_{AS}$ Non Repetitive Avalanche Energy	3.0	mJ	$T_J = 25^\circ\text{C}$ , $I_{AS} = 1.0\text{A}$ , $L = 6\text{mH}$
$I_{AR}$ Repetitive Avalanche Current	0.5	A	Current decaying linearly to zero in 1 $\mu\text{sec}$ Frequency limited by $T_J$ max. $V_a = 1.5 \times V_r$ typical

## Electrical Specifications

Parameters	30BQ	Units	Conditions
$V_{FM}$ Max. Forward Voltage Drop (1)	0.79	V	@ 3A
	0.90	V	@ 6A
	0.62	V	@ 3A
	0.70	V	@ 6A
$I_{RM}$ Max. Reverse Leakage Current (1)	0.5	mA	$T_J = 25^\circ\text{C}$
	5.0	mA	$T_J = 125^\circ\text{C}$
$C_T$ Max. Junction Capacitance	115	pF	$V_R = 5V_{DC}$ (test signal range 100KHz to 1MHz) $25^\circ\text{C}$
$L_S$ Typical Series Inductance	3.0	nH	Measured lead to lead 5mm from package body
dv/dt Max. Voltage Rate of Change	10000	V/ $\mu\text{s}$	(Rated $V_R$ )

(1) Pulse Width < 300 $\mu\text{s}$ , Duty Cycle < 2%

## Thermal-Mechanical Specifications

Parameters	30BQ	Units	Conditions
$T_J$ Max. Junction Temperature Range (*)	-55 to 175	$^\circ\text{C}$	
$T_{stg}$ Max. Storage Temperature Range	-55 to 175	$^\circ\text{C}$	
$R_{thJL}$ Max. Thermal Resistance Junction to Lead (**)	12	$^\circ\text{C/W}$	DCoperation
$R_{thJA}$ Max. Thermal Resistance Junction to Ambient	46	$^\circ\text{C/W}$	DCoperation
wt Approximate Weight	0.24 (0.008)	g(oz.)	
Case Style	SMC		Similar to DO-214AB
Device Marking	IR3J		

(\*)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{th(j-a)}}$  thermal runaway condition for a diode on its own heatsink

(\*\*) Mounted 1 inch square PCB

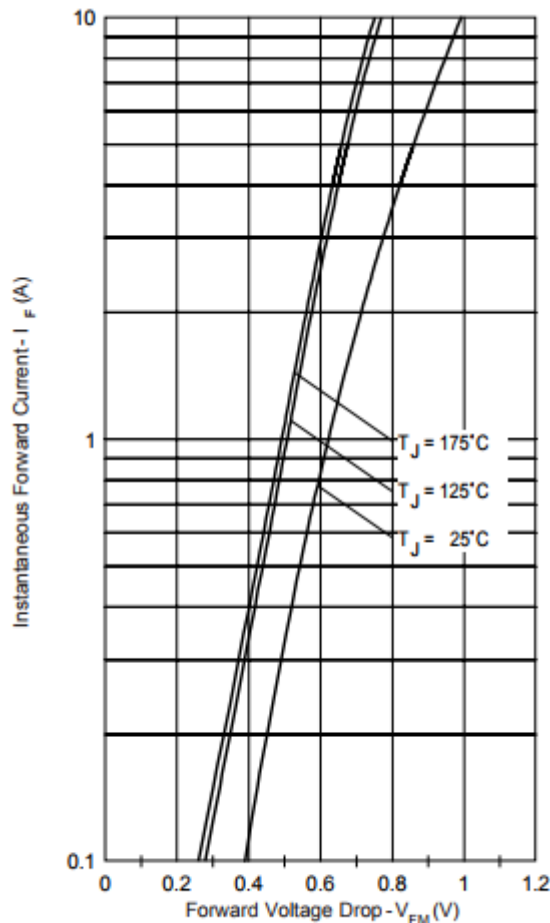


Fig. 1 - Max. Forward Voltage Drop Characteristics (Per Leg)

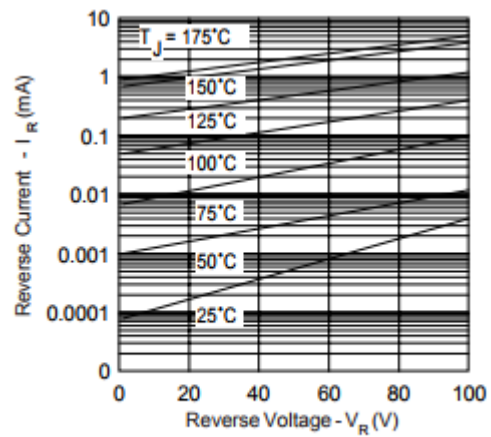


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage (Per Leg)

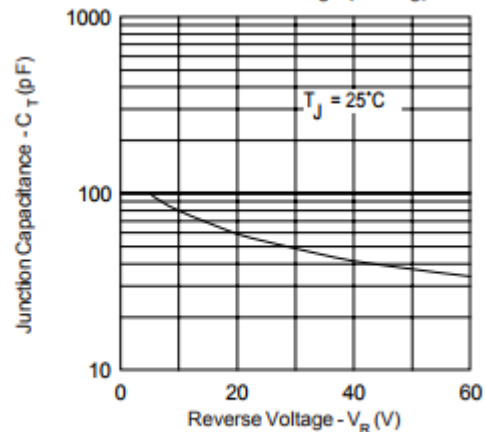


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage (Per Leg)

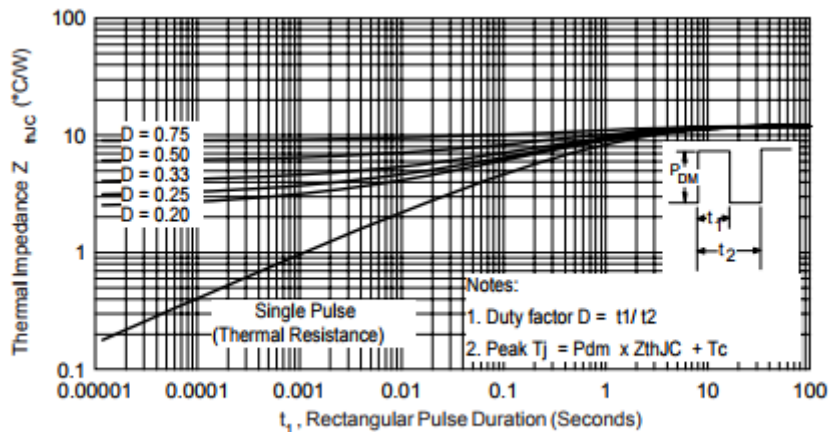
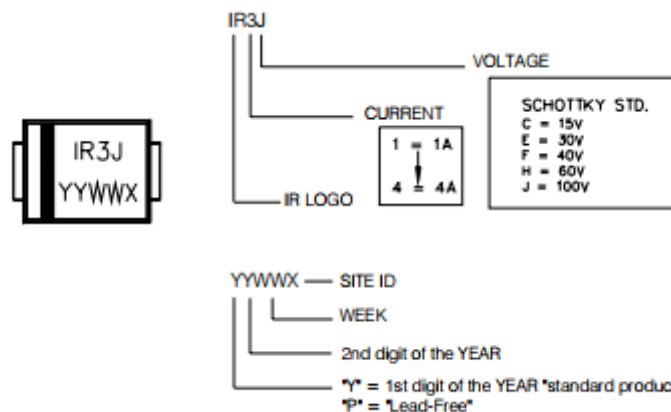


Fig. 4 - Max. Thermal Impedance  $Z_{thJC}$  Characteristics (Per Leg)

Each device has 2 rows for identification. The first row designates the device as manufactured by International Rectifier, indicated by the letters "IR", and the Part Number (indicates the current, the voltage rating and Schottky Generation). The second row indicates the year, the week of manufacturing and the Site ID.

### Marking & Identification



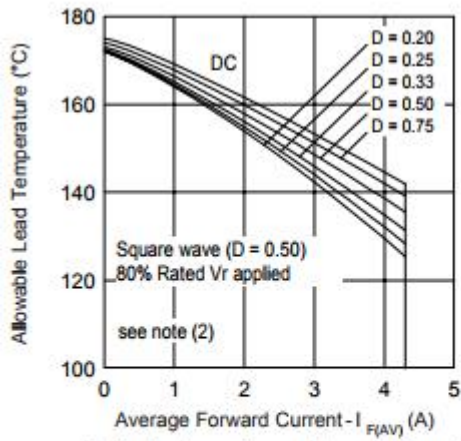


Fig. 4 - Maximum Average Forward Current Vs. Allowable Lead Temperature

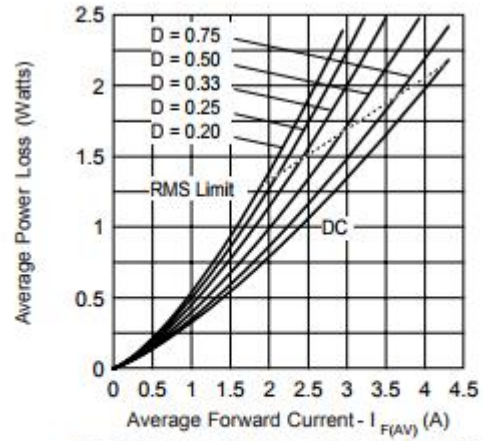


Fig. 5 - Maximum Average Forward Dissipation Vs. Average Forward Current

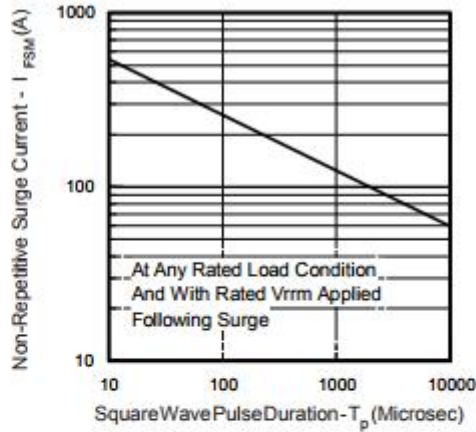
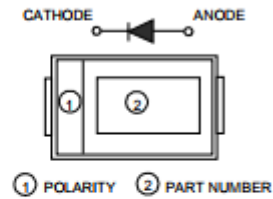
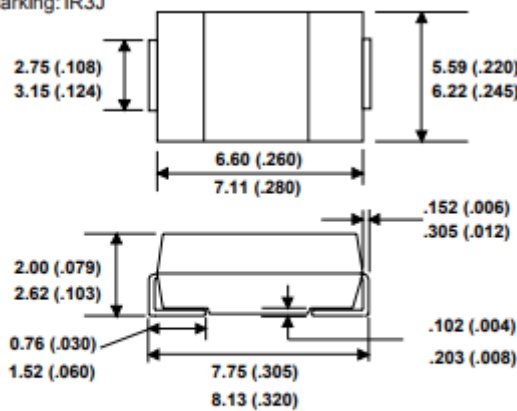


Fig. 6 - Maximum Peak Surge Forward Current Vs. Pulse Duration

- (2) Formula used:  $T_c = T_j - (P_d + P_{d_{REV}}) \times R_{thJC}$ ;  
 $P_d$  = Forward Power Loss =  $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$  (see Fig. 6);  
 $P_{d_{REV}}$  = Inverse Power Loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R @ V_{R1} = 80\%$  rated  $V_R$

Device Marking: IR3J



**Outline SMC**

Dimensions in millimeters and (inches)

For recommended footprint and soldering techniques refer to application note #AN-994